List of Reference Numerals

- 101 substrate
- 103 collector contact
- 5 105 base contact
 - 107 emitter contact
 - 109 BPSG
 - 111 contact via filled with tungsten
- 113 contact via filled with tungsten
- 10 115 contact via filled with tungsten
 - 119 contact via filled with tungsten
 - 121 contact via filled with tungsten
 - 123 contact via filled with tungsten
 - 117 first structured metal plane
- 15 125 second structured metal plane
 - 127 gate polystack
 - 201 substrate
 - 203 substrate surface
 - 205 first terminal
- 20 207 first terminal surface
 - 209 stack
 - 211 second terminal
 - 213 second terminal surface
 - 215 first insulating layer
- 25 217 contact via
 - 219 conductive material
 - 221 second insulating layer
 - 223 etching mask
 - 225 area for a first contact terminal
- 30 227 area for a second contact terminal
 - 229 first recess
 - 231 second recess
 - 233 conductive material
 - 235 conductive material
- 35 237 first contact terminal
 - 239 second contact terminal
 - 301 gate terminal
 - 303 third insulating layer

305 further contact via
307 further contact via
309 conductive material
311 conductive material
5 313 fourth insulating layer
315 third recess
317 fourth recess
319 conductive material
321 conductive material
321 conductive material
401 insulating-layer surface
403 first conductive material
405 second conductive material

407 third conductive material

15